

2SC4868

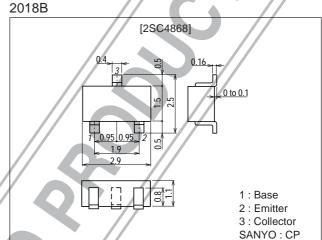
VHF to UHF Wide-Band Low-Noise Amplifier Applications

Features

Low noise: NF=1.2dB typ (f=1GHz).
High gain: |S21e|2=13dB typ (f=1GHz).
High cutoff frequency: f_T=9.0GHz typ.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		16	V
Collector-to-Emitter Voltage	VCEO		8	V
Emitter-to-Base Voltage	VEBO		1.5	V
Collector Current	//I _C		50	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

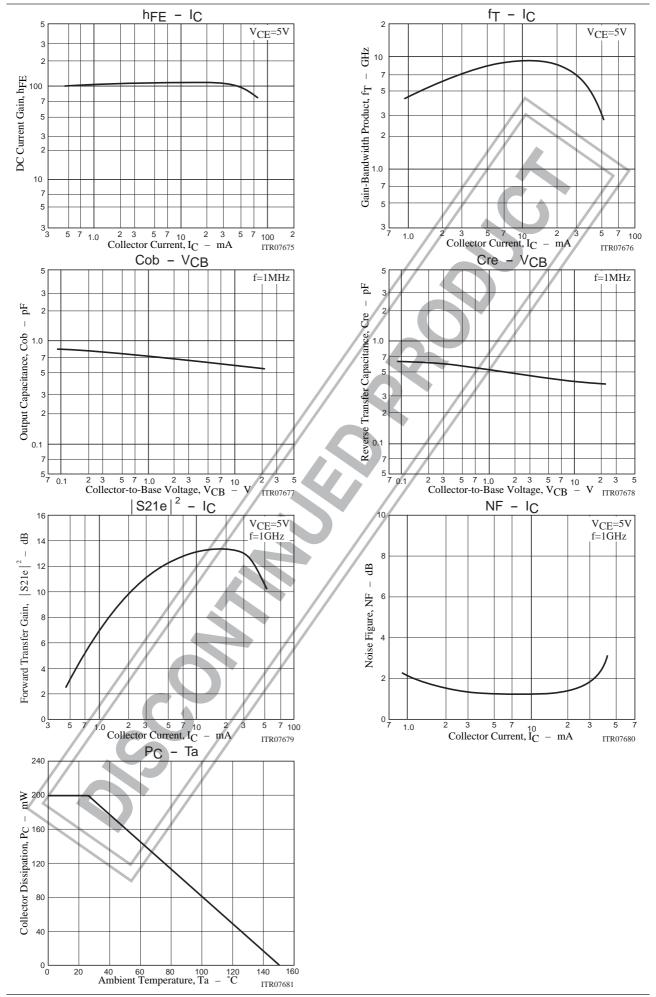
Parameter	Symbol	Conditions	Ratings			Unit
1 arameter	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	Ісво	V _{CB} =10V, I _E =0			1.0	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V, I _C =0			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =15mA	60*		270*	
Gain-Bandwidth Product	fπ	V _{CE} =5V, I _C =15mA		9.0		GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		0.6	1.1	pF
Forward Transfer Gain	S21e 2	V _{CE} =5V, I _C =15mA, f=1GHz	10	13		dB
Noise Figure	NF	V _{CE} =5V, I _C =5mA, f=1GHz		1.2	2.5	dB

 \ast : The 2SC4868 is classified by 15mA h_{FE} as follows : Marking : GN

h_{FE} rank: 3, 4, 5

Rank	3	4	5		
h _{FE}	60 to 120	90 to 180	135 to 270		

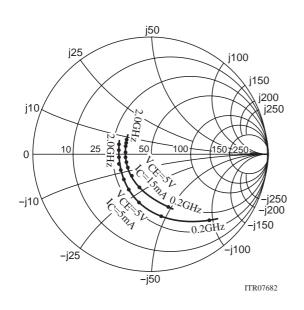
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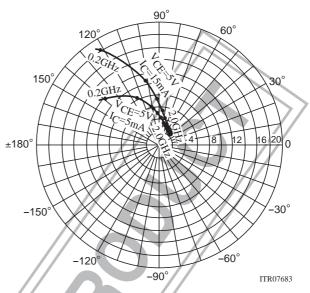


S parameter

f=200MHz to 2000MHz(200MHz Step)

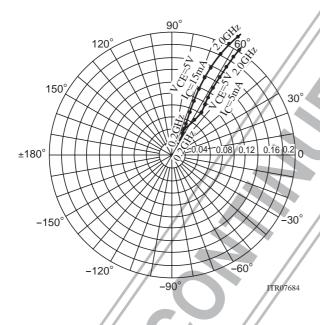


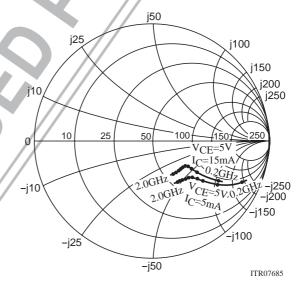




f=200MHz to 2000MHz(200MHz Step)

f=200MHz to 2000MHz(200MHz Step)





S parameter (Common emitter)

 V_{CE} =5V, I_{C} =5mA, Z_{O} =50 Ω

Freq (MHz)	S ₁₁	∠ S ₁₁	S ₂₁	∠ S ₂₁	S ₁₂	∠ S ₁₂	S ₂₂	∠ S ₂₂
200	0.726	-49.0	11.900	139.5	0.045	66.5	0.832	-25.0
400	0.522	-81.9	8.438	115.9	0.070	58.2	0.648	-35.5
600	0.411	-104.5	6.284	101.5	0.086	56.5	0.538	-39.5
800	0.342	-122.0	4.977	91.5	0.102	57.1	0.473	-41.7
1000	0.304	-136.2	4.094	83.7	0.118	57.8	0.448	-44.0
1200	0.278	-150.8	3.498	76.8	0.134	58,8	0.427	-46.0
1400	0.263	-162.9	3.057	70.7	0.151	58.9	0.413	-48.4
1600	0.254	-174.7	2.732	65.3	0.170	58.8	0.400	-51.7
1800	0.252	172.2	2.473	60.2	0.187	58.5	0.391	-55.0
2000	0.253	162.6	2.289	55.4	0.206	58.1	0.387	-58.5

$V_{CE}=5V, I_{C}=15mA, Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠ S ₁₁	S ₂₁	∠ S ₂₁	\$ ₁₂	∠ S ₁₂	S ₂₂	∠ S ₂₂
200	0.454	-74.7	18.146	122.0	0.035	65.4	0.635	-33.9
400	0.295	-110.8	10.672	101.9	0.055	66.1	0.459	-37.3
600	0.243	-132.5	7.405	91.5	0.075	67.8	0.391	-37.1
800	0.219	-149.0	5.706	84.0	0.095	68.5	0.363	-38.0
1000	0.205	-161.4	4.636	78.0	0.117	68.4	0.347	-39.9
1200	0.200	-174.2	3.913	72.4	0.138	67.6	0.340	-42.4
1400	0.200	175.6	3.407	67,7	0.159	66.3	0.334	-45.3
1600	0.202	165.1	3.032	62.9	0.181	64.8	0.327	-49.3
1800	0.209	154.6	2.734	58.5	0.202	63.4	0.322	-53.1
2000	0.215	146.0	2.517	54.3	0.223	61.6	0.319	-57.3

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